

KSA1220/1220A

Audio Frequency Power Amplifier High Frequency Power Amplifier

Complement to KSC2690/KSC2690A



PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Par	rameter	Ratings	Units
V _{CBO}	Collector-Base Voltage	: KSA1220	- 120	V
		: KSA1220A	- 160	V
V _{CEO}	Collector-Emitter Voltage	: KSA1220	- 120	V
020		: KSA1220A	- 160	V
V _{EBO}	Emitter-Base Voltage		- 5	V
I _C	Collector Current (DC)		- 1.2	Α
I _{CP}	*Collector Current (Pulse)		- 2.5	Α
I _B	Base Current		- 0.3	Α
P_{C}	Collector Dissipation (T _a =25°C)		1.2	W
P _C	Collector Dissipation (T _C =25°C)		20	W
T _J	Junction Temperature		150	°C
T _{STG}	Storage Temperature		- 55 ~ 150	°C

^{*} PW≤10ms, Duty Cycle≤50%

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I _{CBO}	Collector Cut-off Current	$V_{CB} = -120V, I_{E} = 0$			- 1	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB} = -3V, I_{C} = 0$			- 1	μΑ
h _{FE1}	* DC Current Gain	$V_{CE} = -5V, I_{C} = -5mA$	35	150		
h _{FE2}		$V_{CE} = -5V, I_{C} = -0.3A$	60	140	320	
V _{CE} (sat)	* Collector-Emitter Saturation Voltage	$I_C = -1A, I_B = -0.2A$		- 0.4	- 0.7	V
V _{BE} (sat)	* Base-Emitter Saturation Voltage	$I_C = -1A, I_B = -0.2A$		- 1	- 1.3	V
f _T	Current Gain Bandwidth Product	$V_{CE} = -5V, I_{C} = -0.2A$		175		MHz
C _{ob}	Output Capacitance	V _{CB} = - 10, I _E = 0 f = 1MHz		26		pF

^{*} Pulse Test: PW≤350μs, Duty Cycle≤2% Pulsed

h_{FE} Classification

Classification	R	0	Υ
h _{FE2}	60 ~ 120	100 ~ 200	160 ~ 320

Typical Characteristics

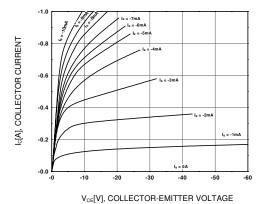


Figure 1. Static Characteristic

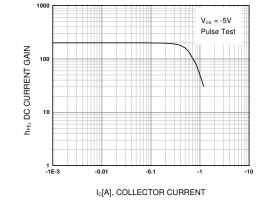


Figure 2. DC current Gain

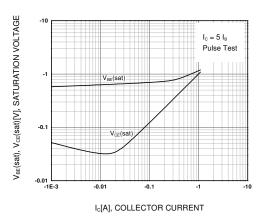


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

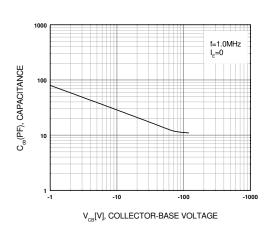


Figure 4. Collector Output Capacitance

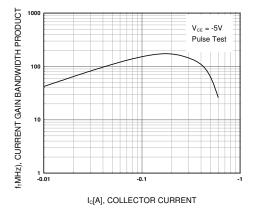


Figure 5. Current Gain Bandwidth Product

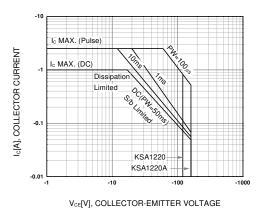


Figure 6. Safe Operating Area

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Typical Characteristics (Continued)

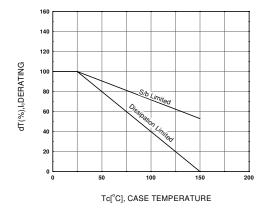


Figure 7. Derating Curve of Safe Operating Areas

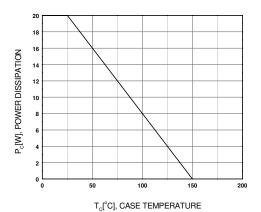
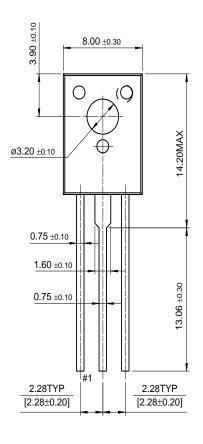
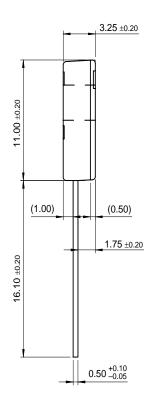


Figure 8. Power Derating

Package Demensions

TO-126





Dimensions in Millimeters

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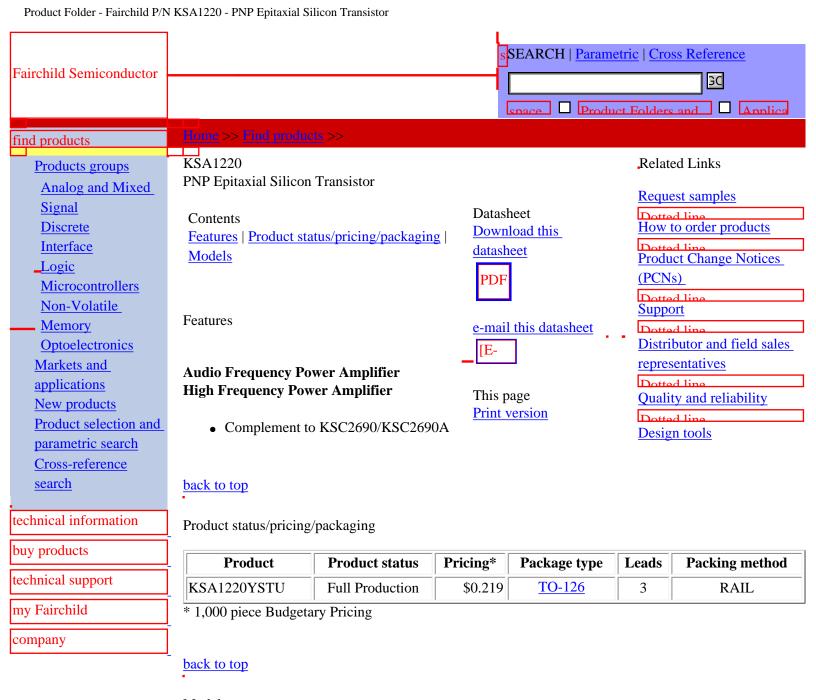
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Models

Package & leads	Condition	Temperature range	Software version	Revision date
PSPICE				
TO-126-3	Electrical/Thermal	-25°C to 100°C	9	Mar 30, 2000

back to top

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